

Title of Change:	FOD819 datasheet update		
Effective date:	26 June 2018		
Contact information:	Contact your local ON Semiconductor Sales Office or <chingaik.yeoh@onsemi.com></chingaik.yeoh@onsemi.com>		
Type of notification:	This Product Bulletin is for notification purposes only. ON Semiconductor will proceed with implementation of this change upon publication of this Product Bulletin.		
Change Category:	Wafer Fab Assembly Change	Test Change V Other <u>DATASHEET</u>	
Change Sub-Category(s): Manufacturing Site Addition Manufacturing Site Transfer Manufacturing Process Changed 	Product specific change	 Datasheet/Product Doc change Shipping/Packaging/Marking Other: 	
Sites Affected:	ON Semiconductor Sites: None	External Foundry/Subcon Sites: None	
Description and Purpose:			
Update FOD819 datasheet specs :			
- The Storage temp, Operating temp and Junction temp from -40degC to -55degC. - Revise the BVCEO from 40V to 80V.			
Improving the product existing specification and performance, so the change will not impact the customer applications.			
The update in datasheet will not impact form, fit, or function of product(s).			
List of Affected Parts:			
FOD819			
FOD819S			
FOD819SD			

Appendix A: Changed Products

Product	Customer Part Number	
FOD819		
FOD819S		
FOD819SD		